

PESDUC3FD5VU

ESD Protector

Description

The PESDUC3FD5VU protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, low operating voltage. It gives designer the flexibility to protect one bi-directional line in applications where arrays are not practical.



Top View

Feature

- DFN1006-3L package
- Unidirectional configurations
- Response time is typically < 1ns</p>
- Low clamping voltage
- Transient protection for data lines to IEC61000-4-2(ESD) ±15KV(air), ±8KV(contact);
 IEC61000-4-4 (EFT) 40A (5/50ns)

Applications

- Cell phone
- > PMP
- > MID
- PDA
- Digital camera
- Other electronics equipments

Mechanical Characteristics

- Lead finish:100% matte Sn(Tin)
- Mounting position: Any
- Qualified max reflow temperature:260°C
- Device meets MSL 2 requirements
- Pure tin plating: 7 ~ 17 um
- ➢ Pin flatness:≤3mil

Electronics Parameter

Symbol	Parameter	
V _{RWM}	Peak Reverse Working Voltage	
I _R	Reverse Leakage Current @ V _{RWM}	
V _{BR}	Breakdown Voltage @ I _T	
IT	Test Current	
I _{PP}	Maximum Reverse Peak Pulse Current	
Vc	Clamping Voltage @ IPP	
P _{PP}	Peak Pulse Power	
CJ	Junction Capacitance	
١ _F	Forward Current	
VF	Forward Voltage @ I _F	



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Absolute maximum rating@25℃

Rating	Symbol	Value	Units
Peak Pulse Power (t _p =8/20µs)	P _{pp}	75	W
Lead Soldering Temperature	TL	260(10 sec)	°C
Operating Temperature	TJ	-55 to +125	°C
Storage Temperature	T _{STG}	-55 to +150	°C

Electrical characteristics per line@25°C(unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	V _{RWM}				5	V
Breakdown Voltage	V _{BR}	I _t =1mA	5.4	7.0	8.5	V
Reverse Leakage Current	I _R	V _{RWM} =5V			1	μA
Forward Voltage	VF	I _F =10mA		0.8	1.25	V
Clamping Voltage	Vc	I _{PP} =1Α t _P = 8/20μS		8	9.2	V
Clamping Voltage	Vc	I _{PP} =5.5A t _P = 8/20µS		13	15	V
Junction Capacitance	Cj	$V_R=0V$ f = 1MHz		0.5	0.8	pF

Typical Characteristics



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Fig 3.Typical Breakdown Voltage vs. Temperature



Fig 5. Clamping voltage vs. Peak pulse current



Fig 4.Typical Leakage Current vs. Temperature



Fig 6. Non-Repetitive Peak Pulse Power vs. Pulse time

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Solder Reflow Recommendation



Peak Temp=257°C, Ramp Rate=0.802deg. °C/sec

PCB Design

For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

- > Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- > Do not make false economies and save copper for the ground connection.
- Place via holes to ground as close as possible to the anode of the TVS diode.
- Use as many via holes as possible for the ground connection.
- Keep the length of via holes in mind! The longer the more inductance they will have.

Product dimension (DFN1006-3L)



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Dim	Millimeters			
Dim	MIN	Тур	МАХ	
А	0.33	0.36	0.50	
В	0.0		0.05	
B1	0.10	0.15	0.20	
B2	0.45	0.50	0.55	
D	0.85	1	1.15	
E	0.45	0.60	0.75	
е		0.35		
L1	0.20	0.25	0.30	
L2	0.21	0.26	0.31	
L3		0.39		



Unit:mm

Ordering information

Device	Package	Shipping
PESDUC3FD5VU	DFN1006-3L (Pb-Free)	10000 / Tape & Reel

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